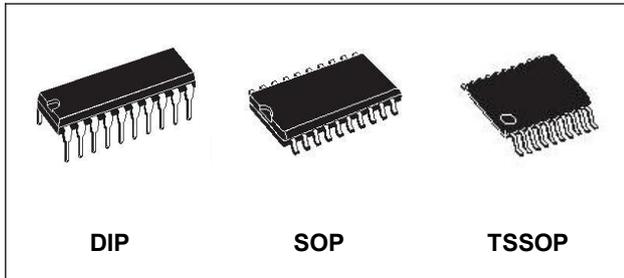


## OCTAL D-TYPE FLIP FLOP WITH 3 STATE OUTPUT NON INVERTING

Datasheet- production data



### Description

The RD74HC574 is a high-speed CMOS OCTAL D-TYPE FLIP FLOP WITH 3-STATE OUTPUTS INVERTING fabricated with sub-micron silicon gate CMOS technology.

This 8 bit D-TYPE FLIP FLOP is controlled by a clock input (CK) and an output enable input ( $\overline{OE}$ ). On the positive transition of the clock, the Q outputs will be set to the logic state that were setup at the D inputs.

While the  $\overline{OE}$  input is at low level, the eight outputs will be in a normal logic state (high or low logic level) and while  $\overline{OE}$  is in high level the outputs will be in a high impedance state.

The output control does not affect the internal operation of flip-flops; that is, the old data can be retained or the new data can be entered even while the outputs are off.

All inputs are equipped with protection circuits against static discharge and transient excess voltage.

### Features

- HIGH SPEED:  
 $f_{MAX} = 90\text{MHz}$  (TYP.) at  $V_{CC} = 6\text{V}$
- LOW POWER DISSIPATION:  
 $I_{CC} = 4\mu\text{A}$  (MAX.) at  $T_A = 25^\circ\text{C}$
- HIGH NOISE IMMUNITY:  
 $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (MIN.)
- SYMMETRICAL OUTPUT IMPEDANCE:  
 $|I_{OH}| = I_{OL} = 6\text{mA}$  (MIN.)
- BALANCED PROPAGATION DELAYS:  
 $t_{PLH} \approx t_{PHL}$
- WIDE OPERATING VOLTAGE RANGE:  
 $V_{CC}(\text{OPR.}) = 2\text{V}$  to  $6\text{V}$

Table 1. Device summary

PART NUMBER	PACKAGE
RD74HC574BDI	DIP20
RD74HC574BSO	SOP20
RD74HC574BTS	TSSOP20

## 1 Pin information

Figure 1. Pin connection and IEC logic symbols

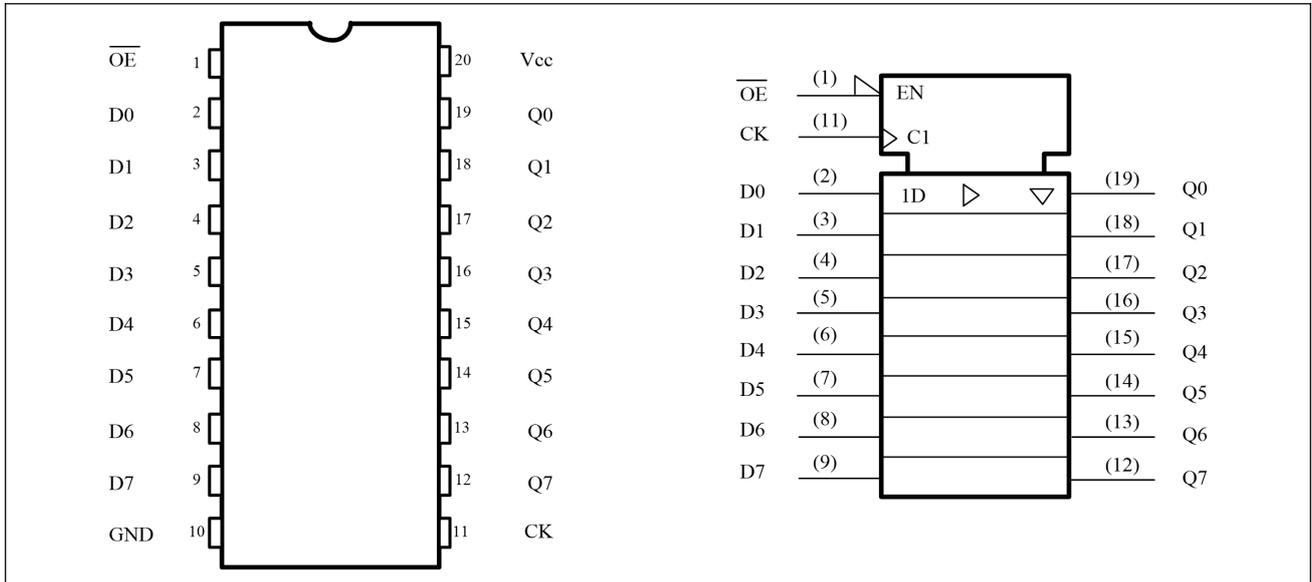


Table 2. Pin description

Pin No	Symbol	Name and function
1	$\overline{\text{OE}}$	3 State Output Enable Input (Active LOW)
2, 3, 4, 5, 6, 7, 8, 9	D0 to D7	Data Inputs
19, 18, 17, 16, 15, 14, 13, 12	Q0 to Q7	3 State Outputs
11	CK	Clock Input (LOW to HIGH, edge triggered)
10	GND	Ground (0V)
20	V <sub>CC</sub>	Positive Supply Voltage

## 2 Functional description

Figure 2. Logic diagram

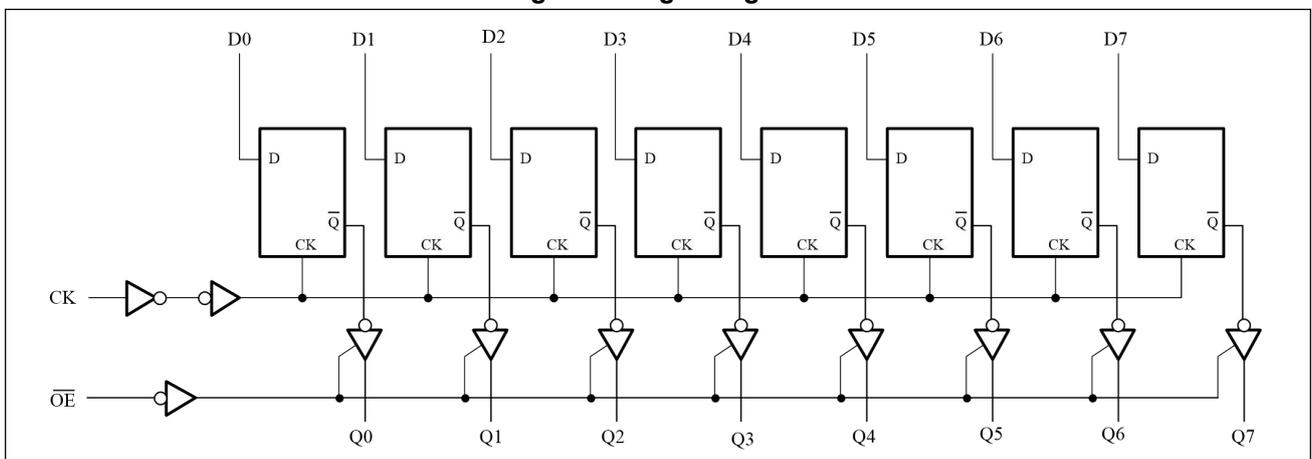


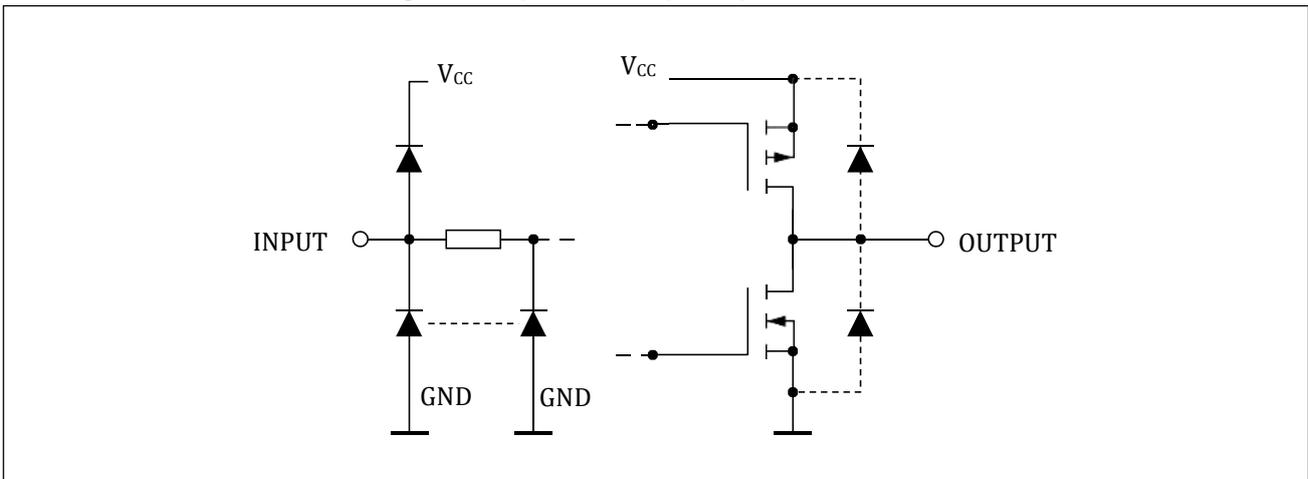
Table 3. Truth table

INPUTS			OUTPUTS
$\overline{OE}$	CK	D	Q
H	X	X	Z
L		X	NO CHANGE
L		L	L
L		H	H

X = Don't care

Z = High impedance

Figure 3. Input and output equivalent circuit



### 3 Electrical characteristics

Table 4. Absolute maximum ratings

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply Voltage	-0.5 to + 7.0	V
$V_I$	DC Input Voltage	-0.5 to $V_{CC} + 0.5$	V
$V_O$	DC Output Voltage	-0.5 to $V_{CC} + 0.5$	V
$I_{IK}$	DC Input Diode Current	$\pm 20$	mA
$I_{OK}$	DC Output Diode Current	$\pm 20$	mA
$I_O$	DC Output Current	$\pm 35$	mA
$I_{CC}$ or $I_{GND}$	DC $V_{CC}$ or Ground Current	$\pm 70$	mA
$P_D$	Power Dissipation	500 (*)	mW
$T_{stg}$	Storage Temperature	-65 to + 150	$^{\circ}C$
$T_L$	Lead Temperature (10 sec)	300	$^{\circ}C$

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied

(\*) 500mW at 65  $^{\circ}C$ ; derate to 300mW by 10mW/ $^{\circ}C$  from 65 $^{\circ}C$  to 85 $^{\circ}C$

Table 5. Recommended operating conditions

Symbol	Parameter		Value	Unit
$V_{CC}$	Supply Voltage		2 to 6	V
$V_I$	Input Voltage		0 to $V_{CC}$	V
$V_O$	Output Voltage		0 to $V_{CC}$	V
$T_{op}$	Operating Temperature		-40 to +85	°C
$t_r, t_f$	Input Rise and Fall Time	$V_{CC} = 2.0V$	0 to 1000	ns
		$V_{CC} = 4.5V$	0 to 500	ns
		$V_{CC} = 6.0V$	0 to 400	ns

Table 6. DC specifications

Symbol	Parameter	Test Condition		Value					Unit
		$V_{CC}$ (V)		$T_A = 25\text{ }^\circ\text{C}$			$-40\text{ to }85\text{ }^\circ\text{C}$		
				Min	Typ	Max	Min	Max	
$V_{IH}$	High Level Input Voltage	2.0		1.5			1.5		V
		4.5		3.15			3.15		
		6.0		4.2			4.2		
$V_{IL}$	Low Level Input Voltage	2.0				0.5		0.5	V
		4.5				1.35		1.35	
		6.0				1.8		1.8	
$V_{OH}$	High Level Output Voltage	2.0	$I_O = -20\mu A$	1.9	2.0		1.9		V
		4.5	$I_O = -20\mu A$	4.4	4.5		4.4		
		6.0	$I_O = -20\mu A$	5.9	6.0		5.9		
		4.5	$I_O = -6.0\text{ mA}$	4.18	4.31		4.13		
		6.0	$I_O = -7.8\text{ mA}$	5.68	5.8		5.63		
$V_{OL}$	Low Level Output Voltage	2.0	$I_O = 20\mu A$		0.0	0.1		0.1	V
		4.5	$I_O = 20\mu A$		0.0	0.1		0.1	
		6.0	$I_O = 20\mu A$		0.0	0.1		0.1	
		4.5	$I_O = 6.0\text{ mA}$		0.17	0.26		0.33	
		6.0	$I_O = 7.8\text{ mA}$		0.18	0.26		0.33	
$I_I$	Input Leakage Current	6.0	$V_I = V_{CC}\text{ or GND}$			$\pm 0.1$		$\pm 1$	$\mu A$
$I_{OZ}$	High Impedance Output Leakage Current	6.0	$V_I = V_{IH}\text{ or }V_{IL}$ $V_O = V_{CC}\text{ or GND}$			$\pm 0.5$		$\pm 5$	$\mu A$
$I_{CC}$	Quiescent Supply Current	6.0	$V_I = V_{CC}\text{ or GND}$			4		40	$\mu A$

Table 7. AC electrical characteristics ( $C_L = 50\text{pF}$ , Input  $t_r = t_f = 6\text{ns}$ )

Symbol	Parameter	Test Condition			Value					Unit
		$V_{CC}$ (V)	$C_L$ (pF)		$T_A = 25^\circ\text{C}$			$-40$ to $85^\circ\text{C}$		
					Min	Typ	Max	Min	Max	
$t_{TLH}t_{THL}$	Output Transition Time	2.0	50		25	60		75	ns	
		4.5		7	12		15			
		6.0		6	10		13			
$t_{PLH}t_{PHL}$	Propagation Delay Time (CK - Q)	2.0	50		70	150		190	ns	
		4.5		20	30		38			
		6.0		15	26		32			
		2.0	150		88	190		240	ns	
		4.5		25	38		48			
		6.0		19	32		41			
$t_{PZL}t_{PZH}$	High Impedance Output Enable Time	2.0	50	$R_L = 1\text{K}\Omega$	48	125		155	ns	
		4.5		15	25		31			
		6.0		12	21		26			
		2.0	150	$R_L = 1\text{K}\Omega$	60	165		205	ns	
		4.5		20	33		41			
		6.0		16	28		35			
$t_{PLZ}t_{PHZ}$	High Impedance Output Disable Time	2.0	50	$R_L = 1\text{K}\Omega$	34	125		155	ns	
		4.5		17	25		31			
		6.0		15	21		26			
$f_{MAX}$	Maximum Clock Frequency	2.0	50		6.2	18		5	MHz	
		4.5		31	75		25			
		6.0		37	90		30			
$t_{W(L)}$ $t_{W(H)}$	Minimum Pulse Width (CLOCK)	2.0	50		15	75		95	ns	
		4.5		6	15		19			
		6.0		6	13		16			
$t_s$	Minimum Set-up Time	2.0	50		25	75		95	ns	
		4.5		6	15		19			
		6.0		4	13		16			
$t_h$	Minimum Hold Time	2.0	50			0		0	ns	
		4.5			0		0			
		6.0			0		0			

Table 8. Capacitive characteristics

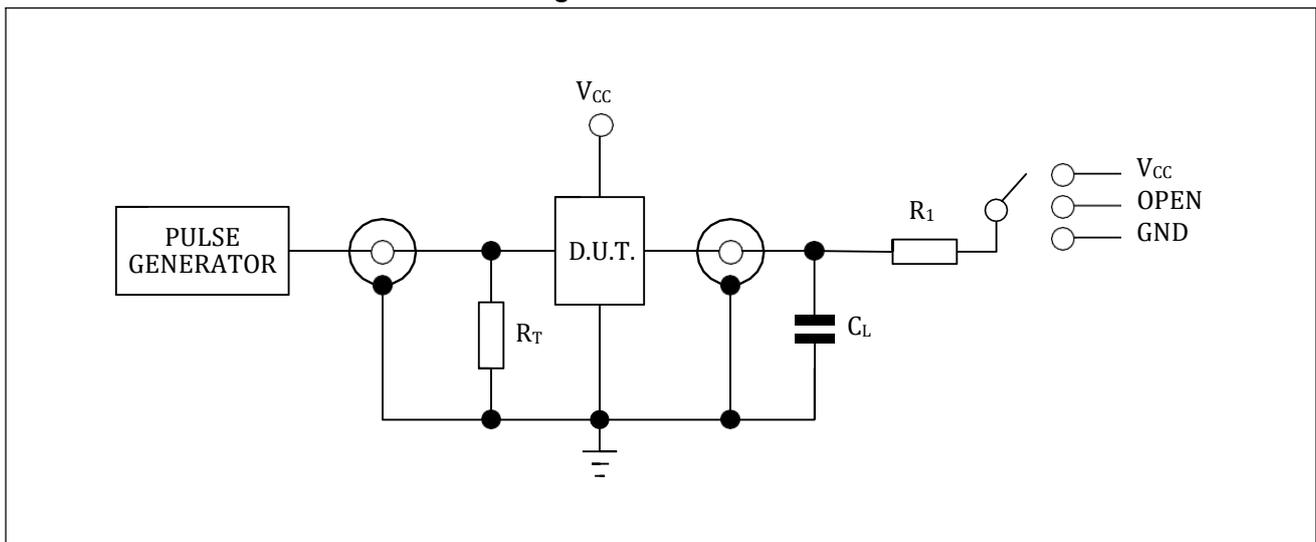
Symbol	Parameter	Test Condition		Value					Unit
		V <sub>CC</sub> (V)		T <sub>A</sub> = 25°C			-40 to 85°C		
				Min	Typ	Max	Min	Max	
C <sub>IN</sub>	Input Capacitance				5	10		10	pF
C <sub>OUT</sub>	Output Capacitance				10				pF
C <sub>PD</sub>	Power Dissipation Capacitance <sup>(1)</sup>				54				pF

1. C<sub>PD</sub> is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to test circuit). Average operating current can be obtained by the following equation:

$$I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$$

## 4 Test circuit

Figure 4. Test circuit



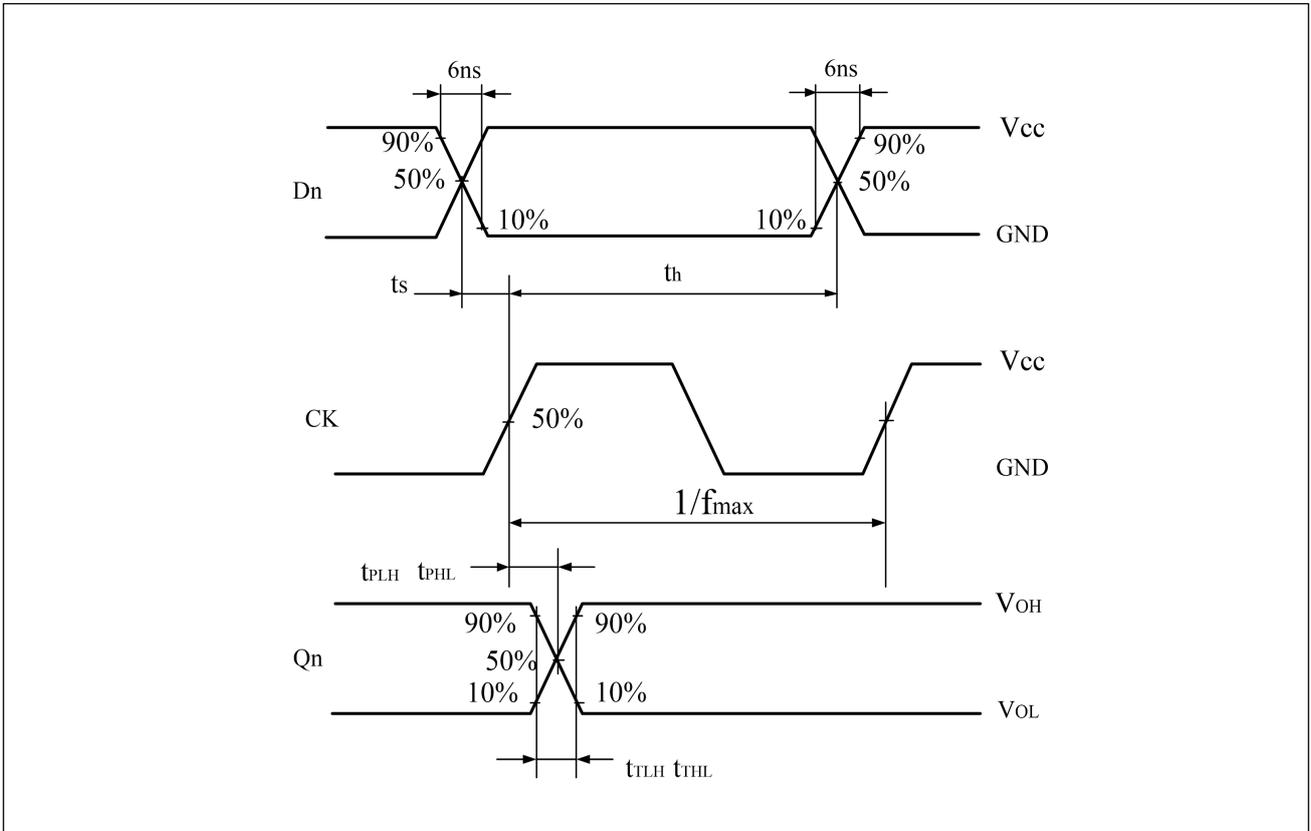
TEST	SWITCH
t <sub>PLH</sub> , t <sub>PHL</sub>	OPEN
t <sub>PZL</sub> , t <sub>PLZ</sub>	V <sub>CC</sub>
t <sub>PZH</sub> , t <sub>PHZ</sub>	GND

R<sub>T</sub> = Z<sub>OUT</sub> of pulse generator (typically 50Ω)

R<sub>1</sub> = 1KΩ or equivalent

C<sub>L</sub> = 50pF/150pF or equivalent (includes jig and probe capacitance)

**Figure 5. Waveform 1: CK to Qn propagation delays, CK maximum frequency, Dn to CK setup and hold times (f=1MHz; 50% duty cycle)**



**Figure 6. Waveform 2: output enable and disable times (f= 1MHz; 50% duty cycle)**

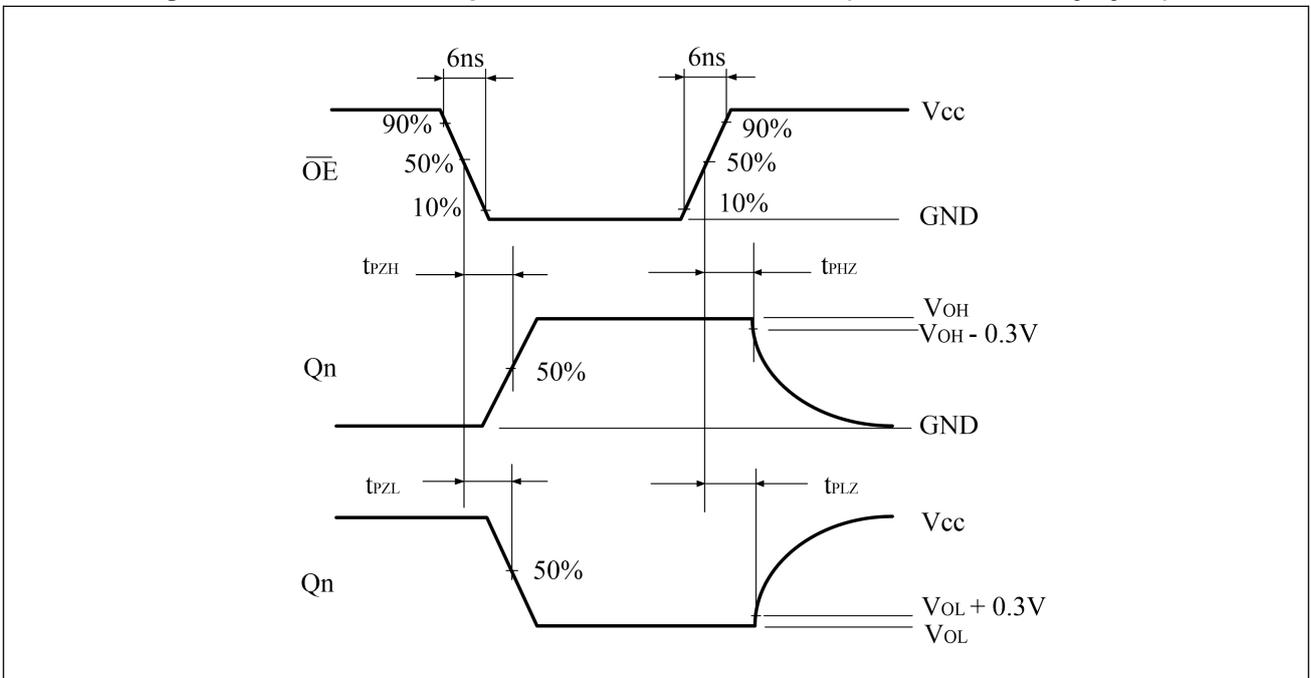
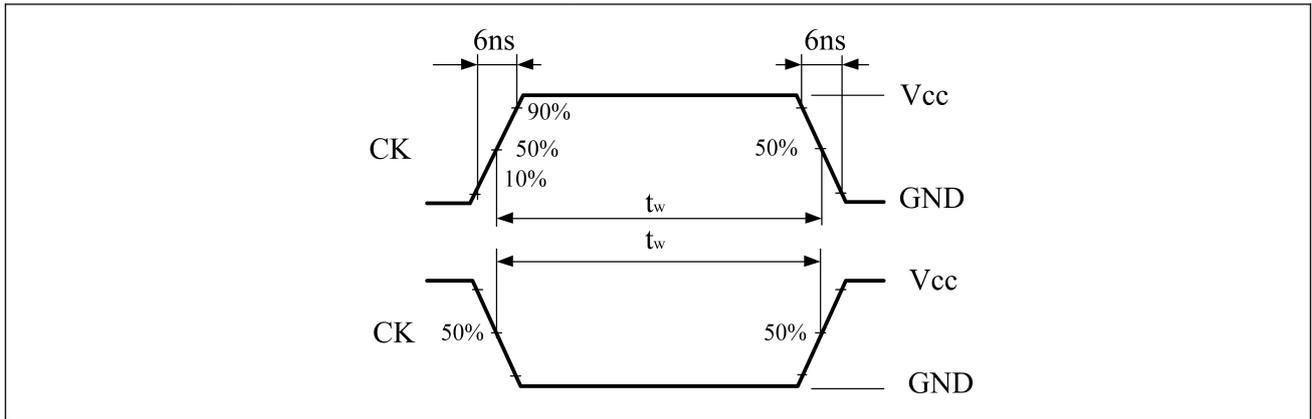


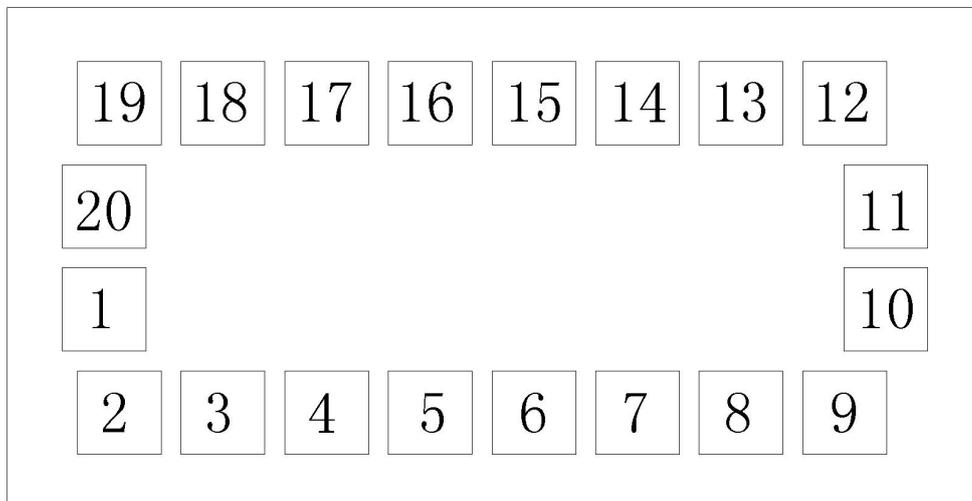
Figure 7. Waveform 3: propagation delay time (f=1MHz; 50% duty cycle)



## 5 Die Information

Die Type	RD74HC574	Wafer Size	8 Inch
Die Size (µm)	X/Y: 657/331	Bond Area (µm)	X/Y: 55/55
Scribeline (µm)	60	Chip Thickness	
Metal	Front	Al+0.5%Cu	
	Back	Si	
	Top Metal Thickness	9000Å	

(640, 331)



(0, 0)

Pin No.	Pin Name	Coordinate		Pin No.	Pin Name	Coordinate	
		X	Y			X	Y
1	$\overline{\text{OE}}$	63.5	131.5	11	CK	576.5	199.5
2	D0	73.5	63.5	12	Q7	549.5	267.5
3	D1	141.5	63.5	13	Q6	481.5	267.5
4	D2	209.5	63.5	14	Q5	413.5	267.5
5	D3	277.5	63.5	15	Q4	345.5	267.5
6	D4	345.5	63.5	16	Q3	277.5	267.5
7	D5	413.5	63.5	17	Q2	209.5	267.5
8	D6	481.5	63.5	18	Q1	141.5	267.5
9	D7	549.5	63.5	19	Q0	73.5	267.5
10	GND	576.5	131.5	20	V <sub>CC</sub>	63.5	199.5

## 6 Ordering information

Table 9. Device summary

Order code	Package	Packing
RD74HC574BDI	DIP20	Tape and reel
RD74HC574BSO	SOP20	
RD74HC574BTS	TSSOP20	
RD74HC574B		Wafer

## 7 Revision history

Table 10. Document revision history <sup>(1)</sup>

Date	Revision	Changes
18-Jan-2022	1	Initial release
12-Dec-2023	2	Added : Die information Revised document presentation, minor textual updates

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